Bismuth plasmonics for extraordinary light absorption in deep sub-wavelength geometries

Imre Ozbay, Amir Ghobadi, Bayram Butun, and Gonul Turhan-Sayan

Department of Electrical and Electronics Engineering, Middle East Technical University, Ankara 06800, Turkey
NANOTAM-Nanotechnology Research Center, Bilkent University, 06800 Ankara, Turkey
Department of Electrical and Electronics Engineering, Bilkent University, 06800 Ankara, Turkey
e-mail: gtsayan@metu.edu.tr
Department of Electrical and Electronics Engineering, Middle East Technical University, Ankara 06800, Turkey

Received 15 October 2019; revised 5 November 2019; accepted 6 November 2019; posted 7 November 2019 (Doc. ID 379670); published 30 January 2020

In this Letter, we demonstrate an ultra-broadband metamaterial absorber of unrivaled bandwidth (BW) using extraordinary optical response of bismuth (Bi), which is the material selected through our novel analysis. Based on our theoretical model, we investigate the maximum metal–insulator–metal (MIM) cavity BW, achievable by any metal with known n-k data. We show that an ideal metal in such structures should have a positive real permittivity part in the near-infrared (NIR) regime. Contrary to noble and lossy metals utilized by most research groups in the field, this requirement is satisfied only by Bi, whose data greatly adhere to the ideal material properties predicted by our analysis. A Bi nanodisc-based MIM resonator with an absorption above 0.9 in an ultra-broadband range of 800 nm–2390 nm is designed, fabricated, and characterized. To the best of our knowledge, this is the broadest absorption BW reported for a MIM cavity in the NIR with its upper-to-lower absorption edge ratio exceeding best contenders by more than 150%. According to the findings in this Letter, the use of proper materials and dimensions will lead to realization of deep sub-wavelength efficient optical devices. © 2020 Optical Society of America

https://doi.org/10.1364/OL.45.000686

In recent years, the concept of plasmonics and metamaterials-based perfect light absorbers (MPAs) has attracted much attention due to their wide range of applications in photovoltaics [1,2], thermal photovoltaics [3,4], photodetectors [5,6], photochemistry [7,8], solar vapor generation [9], imaging [10–12], sensing [13–15], and spectroscopy [16]. Near-unity harvesting of solar irradiation in sub-wavelength geometries, through strong light–matter interaction, can be realized using these MPAs. Metals, with their lossy nature in the whole electromagnetic (EM) spectrum, are the most frequently utilized materials in the MPA design. These ultrathin metal-based MPAs can operate in narrow or broad frequency ranges [17–23]. The narrowband perfect absorbers have potential applications in sensing and filtering, while the broad ones are used in solar vapor generation, photochemistry, and photodetection.

Recently, different materials and design configurations have been proposed to enhance the light absorption bandwidth (BW). The most commonly utilized structure is based on the metal–insulator–metal (MIM) cavity [24–28]. The use of multi-dimensional resonant units and lossy top metals, and adding broadband antireflective coating on top of the MIM design, are some of these ideas [29–34]. However, due to the large negative real part of permittivity ($\varepsilon_{\text{real}}$) of metals in the near-infrared (NIR) region, the absorption in these MIM cavities is limited to the visible regime [35]. Ding et al. proposed a tightly packed titanium-based nanodisc design to achieve perfect light absorption from 900 to 1850 nm [36]. It should be noted that the common strategies for the design of NIR MPA are based on using multiple metal–insulator pairs and nanostructured scaffolds [37,38]. However, these configurations are bulky, and they suffer from complex fabrication routes. In recent years, bismuth (Bi) was found to show extraordinary optical response. Similar to low-loss plasmonic metals, Bi has a small negative $\varepsilon_{\text{real}}$ in the visible range. However, in the NIR regime, it acts as a lossy dielectric with a positive $\varepsilon_{\text{real}}$ [39,40]. The deep sub-wavelength Bi plasmonics were already unveiled in ultraviolet, visible, and NIR regimes [41,42]. Very recently, a deep sub-wavelength (sub $\lambda/100$) nanocavity design has been proposed to achieve perfect narrowband light absorption in the mid-to-far infrared range [43].

Here, we reveal an extraordinary absorption response from the Bi-based MPA. An ultra-broadband, polarization insensitive, and almost omnidirectional NIR perfect absorber will be demonstrated using Bi nanodiscs in an MIM configuration. Based on the transfer matrix method (TMM) modeling estimations, extraordinary response of Bi follows the data of an ideal MIM perfect absorber. The proposed Bi-based MIM nanocavity is designed, fabricated, and characterized. According to the measurement results, the Bi-based MIM cavity can provide above 0.9 the absorption from 700 to 2390 nm in a cavity thicknesses in the order of $\lambda/10$. To the best of our knowledge, this absorption BW is the largest compared to all previously reported MIM-based perfect absorbers. Furthermore, this wavelength range, the short-wave infrared (SWIR), is especially useful for thermal imaging applications, and MIM-based broadband
absorbers have previously been unable to conquer this regime completely (for reasons that we will reveal shortly). Contrary to mainstream semiconductor photodetector technologies such as InGaAs or InP [44,45], which can only cover a portion of the SWIR band with fabrication routines, the findings of this Letter point to the complete coverage of the SWIR band but require low temperatures and complex dielectrics usually have unsophisticated frequency response characteristics, and the back-metal material choice has little effect on overall response as long as it is reflecting. In other words, the search for ideal top metal is the most important part of the search for the ideal device for a given application. To find the ideal top metal, we make no assumptions for the top metal, and instead, we impose the 0.9 absorption for the whole MIM device and solve the TMM equations that yield the “ideal” metal we are looking for. Compared to the finite-difference time-domain (FDTD) method, this enables us to solve thousands of configurations within minutes. In our unique representation, we draw circles that represent the solution domain of the ideal metals for a given configuration of fixed wavelength and fixed dimensions. Materials within this circular domain have a reflection below 0.1 (absorption above 0.9), and thus these can be considered ideal metals for the given configuration. Circles are extracted for three wavelength values of \( \lambda = 1 \) µm, 2 µm, and 3 µm. As we can see, for some configurations around \( \lambda = 1 \) µm, many metals can be utilized as they all fall in the solution domain; however, for \( \lambda \geq 2 \) µm, the circles generally require positive real permittivity, yet almost every metal has a negative real part of permittivity. For this reason, the 700–3000 nm band has never been successfully covered with MIM-based absorbers with conventional metals. However, Bi has a positive real part of permittivity, and therefore, it can take the role of the ideal metal. As can be seen in the panels, Bi outperforms any other metal on the market since it falls inside (or near) a circle for all wavelengths of consideration. Although the findings of this model are valid for a planar design, based on the effective medium theory, a nano unit metal resonator can be roughly treated as an effective medium with an effective permittivity between those of air and metal. This principle can be used to design a top layer that has an effective index between air and Bi, thus providing further flexibility for device optimization. In the next section, it will be demonstrated that ultra-bandwidth perfect absorption can be acquired, using a Bi-nanodiscs-based MIM cavity.

To obtain an optimal device with maximum absorption BW of the design, numerical simulations are conducted (Lumerical FDTD Solutions) [49]. Figure 2(a) depicts the proposed MIM cavity. The optical performance of the cavity can be optimized by studying four main geometrical dimensions: 1) periodicity (\( P \)), 2) spacer thickness (\( D_s \)), 3) disc height (\( D_m \)), and 4) disc radius (\( R \)). The spacer layer is Al2O3, top discs are Bi, and the bottom layer is chromium (Cr). It should be noted that the theoretical TMM and numerical simulation results were extracted using the Cr mirror. This is due to the fabrication considerations as, based on our experiences, Al2O3 has a better surface morphology and adhesion on Cr substrate. Moreover, Cr is rather lossy compared to other metals, and this can consequently substantiate the absorption BW of the design. The experimentally extracted Cr permittivity data have been already reported in our previous work [48]. The unit cell shown in Fig. 2(a) is excited with a plane wave spanning from 700 to 3000 nm in desired polarization and incidence angles.

The aim of the optimization was to obtain an ultra-wide BW that shows little sensitivity to fabrication discrepancies; therefore, instead of an automated method, we used a semi-manual optimization scheme. As can be seen from the results, any variance from the optimal device dimension (\( D_s, D_m, P, \) and \( R \)) does not change our BW more than 2% within our design and fabrication. We found the optimal and stable dimensional region for \( D_s, D_m, P, \) and \( R \) as 145 nm, 25 nm, 600 nm, and 220 nm, respectively. As plotted in Fig. 2(b), when the periodicity increases, while \( D_s, D_m, \) and \( R \) are respectively fixed at 100 nm, 20 nm, and 200 nm, the absorption capability of the
the second peak experiences a red shift. Based on the simulation results in Fig. 2(e), at the optimal $R = 220$ nm, an absorption above 0.9 is accomplished from 800 to 2390 nm. This ultra-broadband BW mainly originates from extraordinary plasmonic response of Bi, together with Fabry–Perot (FP) modes and plasmonic modes.

To gain an insight on the origin of this absorption peak, the magnetic (H) field distributions have been plotted through the cavity length, as shown in Fig. 2(f). The H-field distributions in $\lambda = 960$ nm (the spectral position of first peak) and $\lambda = 2060$ nm (the spectral position of second peak) have been plotted in Figs. 2(g) and 2(h). As plotted in Figs. 2(g) and 2(h), in the first resonance, the magnetic field is mainly confined within the cavity and between two adjacent nanodiscs. However, it is mostly localized beneath the nanodisc unit for the second peak. Therefore, the shorter peak likely originates from diffractive coupling of the incident wave into propagating surface plasmons (SPSs) in the bottom metal–insulator interface. However, the second peak (at 2060 nm) is due to the coupling of incident light into FP-standing waves within the cavity.

Finding the optimal geometries, the design is fabricated and optically characterized. The 150 nm Cr and 25 nm Bi layers are coated using a thermal evaporation tool (Vaksis Ar-Ge). An atomic layer deposition (Cambridge Nanotech Savannah S100) tool is used to coat the Al$_2$O$_3$ spacer. To obtain Bi nanodiscs, the lift-off process was employed. For this purpose, electron beam lithography (RAITH E-Line Plus) was conducted on the sample using the 495 k poly(methyl methacrylate) (PMMA) resist with a thickness of 180 nm. For this process, 30 kV, e-beam spot size of 5 nm, and 350 pA beam current were used. The exposure dose was 3000 pC. The samples were developed by an methyl isobutyl ketone:isopropyl alcohol (MIBK:IPA) (1:1) solution for 2 min, followed by an immersion in IPA for 30 sec.

Figure 3(a) shows a top-view scanning electron microscopy (SEM) image of the sample. To make a comprehensive comparison, the proposed MIM cavity was made for different $R$ values of 200, 210, and 220 nm. Figure 3(b) shows the absorption spectra for these three cases. This optical characterization has been conducted using a Fourier-transform infrared (Bruker, Billerica, MA, USA, HYPERION 2000) system. The agreement between theory and experiment is superb with up to a 99.1% agreement between the experimental and theoretical spectrum. According to this panel, an absorption above 0.9 is attained from 800 nm to 2410 nm (2390 nm theoretically) for the case of $R = 220$ nm. To the best of our knowledge, this is the broadest BW for a MIM-based cavity absorber. Moreover, the proposed design has a quite high angular absorption response. As depicted in Figs. 3(c) and 3(d), the strong absorption response of the design is retained in wide viewing angles for both transverse electric (TE) and transverse magnetic (TM) polarizations.

In summary, this work reveals the extraordinary capability of Bi to obtain perfect light absorption in the ultra-broadband wavelength range. It was found that the real part of permittivity for Bi has small negative values in visible and short wavelength NIR ranges. However, in moving toward longer wavelength values, these data follow a gradual increase toward larger positive amounts. According to our previous study, this is in good agreement with the permittivity data of an ideal unity absorber. With numerical simulations, the proposed MIM cavity is optimized in a way that the broadest absorption BW is achieved. This optimal configuration is fabricated and optically characterized.
According to our findings, an absorption BW of 1610 nm is acquired in the MIM cavity thicknesses in the order of λ/10. The simulation results also demonstrate that the proposed design has a high angular tolerance for both TE and TM polarizations. The findings of this study can be applied to other devices over the complete NIR range (1–30 µm) using proper topology and proper geometry.

Disclosures. The authors declare no conflicts of interest.

REFERENCES